

SNIS176 - MARCH 2013 www.ti.com

LMT89 2.4V, 10µA, SC70, Temperature Sensor

Check for Samples: LMT89

FEATURES

- **Cost-Effective Alternative to Thermistors**
- Rated for full -55°C to +130°C range
- Available in an SC70 Package
- **Predictable Curvature Error**
- **Suitable for Remote Applications**

APPLICATIONS

- Industrial
- **HVAC**
- **Automotive**
- **Disk Drives**
- **Portable Medical Instruments**
- Computers
- **Battery Management**
- **Printers**
- **Power Supply Modules**
- **FAX Machines**
- **Mobile Phones**
- **Automotive**

DESCRIPTION

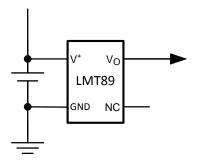
The LMT89 is a precision analog output CMOS integrated-circuit temperature sensor that operates over a -55°C to 130°C temperature range. The power supply operating range is 2.4 V to 5.5 V. The transfer function of LMT89 is predominately linear, yet has a slight predictable parabolic curvature. The accuracy of the LMT89 when specified to a parabolic transfer function is ±1.5°C at an ambient temperature of 30°C. The temperature error increases linearly and reaches a maximum of ±2.5°C at the temperature range extremes. The temperature range is affected by the power supply voltage. At a power supply voltage of 2.7 V to 5.5 V the temperature range extremes are 130°C and -55°C. Decreasing the power supply voltage to 2.4 V changes the negative extreme to -30°C, while the positive remains at 130°C.

The LMT89 guiescent current is less than 10 µA. Therefore, self-heating is less than 0.02°C in still air. Shutdown capability for the LMT89 is intrinsic because its inherent low power consumption allows it to be powered directly from the output of many logic gates or does not necessitate shutdown at all.

The LMT89 is a cost-competitive alternative to thermistors.

TYPICAL APPLICATION

Full-Range Celsius (Centigrade) Temperature Sensor (-55°C TO 130°C) Operating From a Single LI-Ion **Battery Cell**



$$V_O = (-3.88 \times 10^{-6} \times T^2) + (-1.15 \times 10^{-2} \times T) + 1.8639$$

$$T = -1481.96 + \sqrt{2.1962 \times 10^6 + \frac{(1.8639 - V_0)}{3.88 \times 10^{-6}}}$$

where: T is temperature, and V_O is the measured output voltage of the LMT89.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

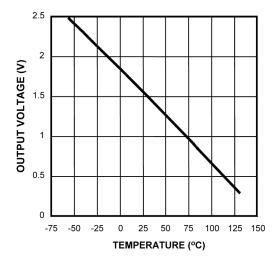


Figure 1. Output Voltage vs Temperature

Table 1. Output Voltage vs Temperature

TEMPERATURE (T)	TYPICAL V _O
130°C	303 mV
100°C	675 mV
80°C	919 mV
30°C	1515 mV
25°C	1574 mV
0°C	1863.9 mV
−30°C	2205 mV
-40°C	2318 mV
−55°C	2485 mV

CONNECTION DIAGRAMS



GND (pin 2) may be grounded or left floating. For optimum thermal conductivity to the pc board ground plane, pin 2 must be grounded.

NC (pin 1) must be left floating or grounded. Other signal traces must not be connected to this pin.

Figure 2. SC70-5 Top View

www.ti.com SNIS176 – MARCH 2013

ABSOLUTE MAXIMUM RATINGS(1)

		VALUES
Supply Voltage		6.5V to −0.2V
Output Voltage		(V ⁺ + 0.6 V) to −0.6 V
Output Current		10 mA
Input Current at any pin (2)		5 mA
Storage Temperature		−65°C to 150°C
Maximum Junction Tempera	ature (T _{JMAX})	150°C
ECD Consentibility (3)	Human Body Model	2500 V
ESD Susceptibility (3)	Machine Model	250 V
Soldering process must cor	nply with the Reflow Temperature Profile specifications.	Refer to www.ti.com/packaging. ⁽⁴⁾

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For specifications and test conditions, see the ELECTRICAL CHARACTERISTICS. The specified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) When the input voltage (V_1) at any pin exceeds power supplies $(V_1 < GND \text{ or } V_1 > V^+)$, the current at that pin should be limited to 5 mA.
- (3) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.
- (4) Reflow temperature profiles are different for lead-free and non-lead-free packages.

OPERATION RATINGS

Specified Temperature Range:	$T_{MIN} \le T_A \le T_{MAX}$
LMT89 with 2.4 V ≤ V ⁺ ≤ 2.7 V	-30°C ≤ T _A ≤ 130°C
LMT89 with 2.7 V ≤ V ⁺ ≤ 5.5 V	-55°C ≤ T _A ≤ 130°C
Supply Voltage Range (V ⁺)	2.4 V to 5.5 V
Thermal Resistance, $\theta_{JA}^{(1)}$	
SC70	415°C/W

(1) The junction to ambient thermal resistance (θ_{JA}) is specified without a heat sink in still air using the printed circuit board layout shown in PCB Layouts Used For Thermal Measurements.

Product Folder Links: LMT89

SNIS176-MARCH 2013 www.ti.com

ELECTRICAL CHARACTERISTICS

Unless otherwise noted, these specifications apply for $V^+ = +2.7 V_{DC}$. Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25$ °C; Unless otherwise noted.

PARAMETER	CONDITIONS	TYPICAL ⁽¹⁾	MAX ⁽²⁾	UNIT (Limit)
Temperature to Voltage Error	T _A = 25°C to 30°C	±1.5		°C
$V_O = (-3.88 \times 10^{-6} \times T^2) + (-1.15 \times 10^{-2} \times T) + 1.8639 V^{(3)}$	$T_A = -55$ °C		±2.5	°C
Output Voltage at 0°C		1.8639		V
Variance from Curve		±1.0		°C
Non-Linearity (4)	-20°C ≤ T _A ≤ 80°C	±0.4%		
Sensor Gain (Temperature Sensitivity or Average Slope) to equation: V _O =-11.77 mV/ °CxT+1.860V	-30°C ≤ T _A ≤ 100°C	-11.77	-11.4 -12.2	mV/°C (min) mV/°C (max)
Output Impedance	$0 \mu A \le I_L \le 16 \mu A^{(5)(6)}$		160	Ω
Load Regulation (7)	0 μA ≤ I _L ≤ 16 μA ^{(5) (6)}		-2.5	mV
Line Degulation (8)	2.4 V ≤ V ⁺ ≤ 5.0V		3.3	mV/V
Line Regulation ⁽⁸⁾	5.0 V ≤ V ⁺ ≤ 5.5 V		11	mV
	2.4V ≤ V ⁺ ≤ 5.0V	4.5	7	μΑ
Quiescent Current	5.0V ≤ V ⁺ ≤ 5.5V	4.5	9	μΑ
	2.4V ≤ V ⁺ ≤ 5.0V	4.5	10	μΑ
Change of Quiescent Current	2.4 V ≤ V ⁺ ≤ 5.5V	0.7		μΑ
Temperature Coefficient of Quiescent Current		-11		nA/°C
Shutdown Current	V ⁺ ≤ 0.8 V	0.02		μΑ

- Typicals are at T_J = T_A = 25°C and represent most likely parametric norm. Limits are specified to Tl's AOQL (Average Outgoing Quality Level).
- Accuracy is defined as the error between the measured and calculated output voltage at the specified conditions of voltage, current, and temperature (expressed in°C).
- Non-Linearity is defined as the deviation of the calculated output-voltage-versus-temperature curve from the best-fit straight line, over the temperature range specified.
- Negative currents are flowing into the LMT89. Positive currents are flowing out of the LMT89. Using this convention the LMT89 can at most sink -1 μA and source 16 μA.
- Load regulation or output impedance specifications apply over the supply voltage range of 2.4V to 5.5V.
- Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.
- Line regulation is calculated by subtracting the output voltage at the highest supply input voltage from the output voltage at the lowest supply input voltage.

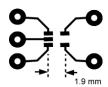
Submit Documentation Feedback



www.ti.com SNIS176 – MARCH 2013

TYPICAL PERFORMANCE CHARACTERISTICS

PCB Layouts Used For Thermal Measurements



TEMPERATURE (°C)

Figure 3. Layout Used For No Heat Sink Measurements



Figure 4. Layout Used For Measurements With Small Heat Sink

LMT89 TRANSFER FUNCTION

The LMT89 transfer function can be described in different ways with varying levels of precision. A simple linear transfer function, with good accuracy near 25°C, is

$$V_{O} = -11.69 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8663 \text{ V}$$
 (1)

Over the full operating temperature range of -55°C to 130°C, best accuracy can be obtained by using the parabolic transfer function.

$$V_{O} = (-3.88 \times 10^{-6} \times T^{2}) + (-1.15 \times 10^{-2} \times T) + 1.8639$$
 (2)

solving for T:

$$T = -1481.96 + \sqrt{2.1962 \times 10^6 + \frac{(1.8639 - V_O)}{3.88 \times 10^{-6}}}$$
(3)

A linear transfer function can be used over a limited temperature range by calculating a slope and offset that give best results over that range. A linear transfer function can be calculated from the parabolic transfer function of the LMT89. The slope of the linear transfer function can be calculated using the following equation:

$$m = -7.76 \times 10^{-6} \times T - 0.0115, \tag{4}$$

where T is the middle of the temperature range of interest and m is in V/°C. For example for the temperature range of $T_{MIN} = -30$ to $T_{MAX} = +100$ °C:

$$T = 35^{\circ}C \tag{5}$$

and

$$m = -11.77 \text{ mV/}^{\circ}\text{C}$$
 (6)

The offset of the linear transfer function can be calculated using the following equation:

SNIS176 – MARCH 2013 www.ti.com

$$b = (V_{OP}(T_{MAX}) + V_{OP}(T) - m \times (T_{MAX} + T))/2$$

(7)

where:

 $V_{OP}(T_{MAX})$ is the calculated output voltage at T_{MAX} using the parabolic transfer function for $V_{OP}(T)$ is the calculated output voltage at T using the parabolic transfer function for $V_{OP}(T)$.

Using this procedure the best fit linear transfer function for many popular temperature ranges was calculated in Table 2. As shown in Table 2 the error that is introduced by the linear transfer function increases with wider temperature ranges.

Table 2. First Order Equations Optimized for Different Temperature Ranges

TEMPERAT	URE RANGE	LINEAR EQUATION	MAXIMUM DEVIATION OF LINEAR EQUATION				
T _{min} (°C)	T _{max} (°C)	LINEAR EQUATION	FROM PARABOLIC EQUATION (°C)				
-55	130	$V_O = -11.79 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8528 \text{ V}$	±1.41				
-40	110	$V_O = -11.77 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8577 \text{ V}$	±0.93				
-30	100	$V_O = -11.77 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8605 \text{ V}$	±0.70				
-40	85	$V_O = -11.67 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8583 \text{ V}$	±0.65				
-10	65	$V_O = -11.71 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8641 \text{ V}$	±0.23				
35	45	$V_O = -11.81 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8701 \text{ V}$	±0.004				
20	30	$V_O = -11.69 \text{ mV/}^{\circ}\text{C} \times \text{T} + 1.8663 \text{ V}$	±0.004				

MOUNTING

The LMT89 can be applied easily in the same way as other integrated-circuit temperature sensors. It can be glued or cemented to a surface. The temperature that the LMT89 is sensing will be within about +0.02°C of the surface temperature to which the LMT89's leads are attached to.

This presumes that the ambient air temperature is almost the same as the surface temperature; if the air temperature were much higher or lower than the surface temperature, the actual temperature measured would be at an intermediate temperature between the surface temperature and the air temperature.

To ensure good thermal conductivity the backside of the LMT89 die is directly attached to the pin 2 GND pin. The tempertures of the lands and traces to the other leads of the LMT89 will also affect the temperature that is being sensed.

Alternatively, the LMT89 can be mounted inside a sealed-end metal tube, and can then be dipped into a bath or screwed into a threaded hole in a tank. As with any IC, the LMT89 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. Printed-circuit coatings and varnishes such as Humiseal and epoxy paints or dips are often used to ensure that moisture cannot corrode the LMT89 or its connections.

The thermal resistance junction to ambient (θ_{JA}) is the parameter used to calculate the rise of a device junction temperature due to its power dissipation. For the LMT89 the equation used to calculate the rise in the die temperature is as follows:

$$T_J = T_A + \theta_{JA} [(V^+ I_Q) + (V^+ - V_O) I_L]$$

where I_Q is the quiescent current and I_L is the load current on the output. Since the LMT89's junction temperature is the actual temperature being measured care should be taken to minimize the load current that the LMT89 is required to drive.

The tables shown in Table 3 summarize the rise in die temperature of the LMT89 without any loading, and the thermal resistance for different conditions.

www.ti.com SNIS176 – MARCH 2013

Table 3. Telliberature Nise of Livi 103 Due to Sell'Heatillu allu Tilerillai Nesistalice (Dixi) (Table 3. Temperature Rise	of LMT89 Due to Self-H	leating and Thermal	Resistance (θ _{ιλ}) ⁽¹⁾
---	---------------------------	------------------------	---------------------	--

	S	C70-5	SC70-5				
	NO H	EAT SINK	SMALL HEAT SINK				
	θ _{JA} (°C/W)	T _J - T _A (°C)	θ _{JA} (°C/W)	T _J – T _A (°C)			
Still air	412	0.2	350	0.19			
Moving air	312	0.17	266	0.15			

⁽¹⁾ See PCB Layouts Used For Thermal Measurements for PCB layout samples.

CAPACITIVE LOADS

The LMT89 handles capacitive loading well. Without any precautions, the LMT89 can drive any capacitive load less than 300 pF as shown in . Over the specified temperature range the LMT89 has a maximum output impedance of 160 Ω . In an extremely noisy environment it may be necessary to add some filtering to minimize noise pickup. It is recommended that 0.1 μ F be added from V⁺ to GND to bypass the power supply voltage, as shown in Figure 5. In a noisy environment it may even be necessary to add a capacitor from the output to ground with a series resistor as shown in Figure 5. A 1 μ F output capacitor with the 160 Ω maximum output impedance and a 200 Ω series resistor will form a 442 Hz lowpass filter. Since the thermal time constant of the LMT89 is much slower, the overall response time of the LMT89 will not be significantly affected.

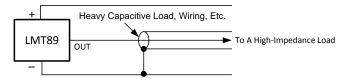


Figure 5. LMT89 No Decoupling Required for Capacitive Loads Less Than 300 pF

R (Ω)	C (μF)
200	1
470	0.1
680	0.01
1 k	0.001

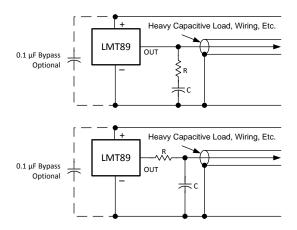


Figure 6. LMT89 with Filter for Noisy Environment and Capacitive Loading Greater Than 300 pF

NOTE

Either placement of resistor as shown above is just as effective.

Copyright © 2013, Texas Instruments Incorporated

SNIS176 – MARCH 2013 www.ti.com



APPLICATION CIRCUITS

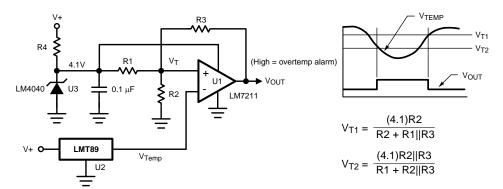


Figure 7. Centigrade Thermostat

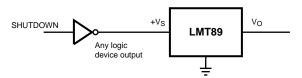


Figure 8. Conserving Power Dissipation with Shutdown

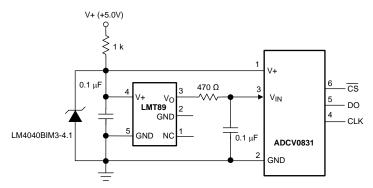


Figure 9. Suggested Connection to a Sampling Analog to Digital Converter Input Stage

Most CMOS ADCs found in ASICs have a sampled data comparator input structure that is notorious for causing grief to analog output devices such as the LMT89 and many op amps. The cause of this grief is the requirement of instantaneous charge of the input sampling capacitor in the ADC. This requirement is easily accommodated by the addition of a capacitor. Since not all ADCs have identical input stages, the charge requirements will vary necessitating a different value of compensating capacitor. This ADC is shown as an example only. If a digital output temperature is required please refer to devices such as the LM74.

Submit Documentation Feedback



PACKAGE OPTION ADDENDUM

11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
LMT89DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 130	Т3В	Samples
LMT89DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 130	T3B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 8-Apr-2013

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMT89DCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMT89DCKT	SC70	DCK	5	250	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3

www.ti.com 8-Apr-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMT89DCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LMT89DCKT	SC70	DCK	5	250	210.0	185.0	35.0

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com/omap

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>